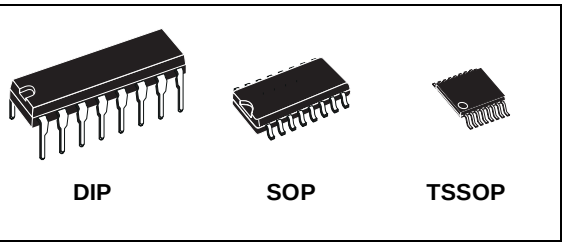
M74HC4316

QUAD BILATERAL SWITCH

- HIGH SPEED:
  t_{PD} = 13ns (TYP.) at V_{CC} = 6V
- LOW POWER DISSIPATION:
  I_{CC} = 1µA(MAX.) at V_{cc} = 5V
- LOW "ON" RESISTANCE:
  120Ω TYP. (V_{CC} - V_{EE} = 2V)
  50Ω TYP. (V_{CC} - V_{EE} = 4.5V)
  35Ω TYP. (V_{CC} - V_{EE} = 9V)
- WIDE ANALOG INPUT VOLTAGE RANGE ± 6v
- LOW CROSSTALK BETWEEN SWITCHES
- FAST SWITCHING
- SINE WAVE DISTORTION:
  0.020 at V_{CC} - V_{EE} = 9V
- HIGH NOISE IMMUNITY:
  V_{NIH} = V_{NIL} = 28 % V_{CC} (MIN.)
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 4316



DIP **SOP** **TSSOP**

ORDER CODES

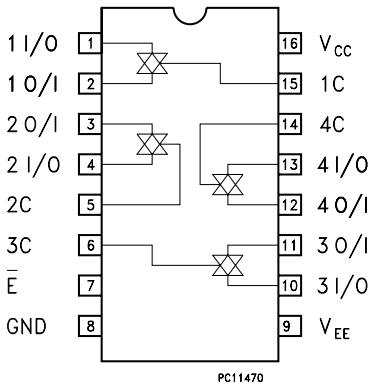
PACKAGE	TUBE	T & R
DIP	M74HC4316B1R	
SOP	M74HC4316M1R	M74HC4316RM13TR
TSSOP		M74HC4316TTR

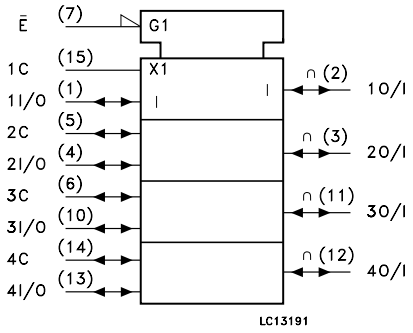
DESCRIPTION

The M74HC4316 is an high speed CMOS QUAD BILATERAL SWITCH fabricated with silicon gate C^2MOS technology.
This device has four independent analogue switches. Each switch has two input/output terminals (nI/O, nO/I) and an active high select input (nC).

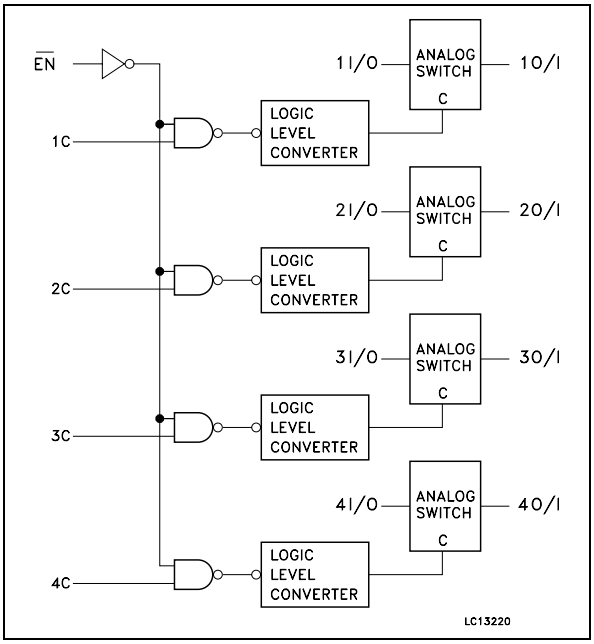
When the enable input is high, all four analog switches are off. The supply voltage for the digital signals applied to V_{CC} and GND must be whitin the range 0 to 6 V. The voltage swing on the analogue Inputs/Outputs can be between V_{CC} (positive limit) and V_{EE} (negative limit). The voltage between V_{CC} and V_{EE} must not exceed 12V.
All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS





LOGIC DIAGRAM



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 4, 10, 13	1 to 4 I/O	Independent Inputs/Outputs
2, 3, 11, 12	1 to 4 O/I	Independent Outputs/ Inputs
7	$\overline{E}$	Enable Inputs (Active LOW)
15, 5, 6, 14	1C to 4C	Enable Inputs (Active High)
9	V_{EE}	Negative Supply Voltage
8	GND	Ground (0V)
16	V_{CC}	Positive Supply Voltage

TRUTH TABLE

$\overline{E}$	C	SWITCH FUNCTION
L	H	ON
L	L	OFF
H	X	OFF

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_{CC} - V_{EE}	Supply Voltage	-0.5 to +13	V
V_I	Control Input Voltage	-0.5 to V_{CC} + 0.5	V
$V_{I/O}$	Switch Input/Output Voltage	V_{EE} -0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500(*)	mW
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied
(*) 500mW at 65 °C; derate to 300mW by 10mW/°C from 65°C to 85°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage		2 to 12	V
V_{EE}	Supply Voltage		-6 to 0	V
V_{CC} - V_{EE}	Supply Voltage		2 to 12	V
V_I	Input Voltage		0 to V_{CC}	V
$V_{I/O}$	Switch I/O Voltage		0 to V_{CC}	V
T_{op}	Operating Temperature		-55 to 125	°C
t_r, t_f	Input Rise and Fall Time	V_{CC} = 2.0V	0 to 1000	ns
		V_{CC} = 4.5V	0 to 500	
		V_{CC} = 6.0V	0 to 400	

DC SPECIFICATIONS

Symbol	Parameter	Test Condition			Value							Unit
		V_{CC} (V)	V_{EE} (V)		T_A = 25°C			-40 to 85°C		-55 to 125°C		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IHC}	High Level Control Input Voltage	2.0			1.5			1.5		1.5		V
		4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
V_{ILC}	Low Level Control Input Voltage	2.0					0.5		0.5		0.5	V
		4.5					1.35		1.35		1.35	
		6.0					1.8		1.8		1.8	
R_{ON}	ON Resistance	4.5	GND	$V_I = V_{IHC}$ $V_{I/O} = V_{CC}$ to V_{EE} $I_{I/O}$ = 0.1mA		70	170		200			Ω
		4.5	-4.5			50	85		105			
		6.0	-6.0			30	70		85			
		2.0	GND	$V_I = V_{IHC}$ $V_{I/O} = V_{CC}$ or V_{EE} $I_{I/O}$ = 0.1mA		120	180		215			
		4.5	GND			50	80		100			
		4.5	-4.5			35	60		75			
		6.0	-6.0			20	40		60			
ΔR_{ON}	Difference of ON Resistance between switches	4.5	GND	$V_{IN} = V_{IHC}$ or V_{ILC} $V_{I/O} = V_{CC}$ to V_{EE} $I_{I/O}$ = 0.1mA		10	15		20			Ω
		4.5	-4.5			5	10		15			
		6.0	-6.0			5	10		15			
I_{OFF}	Input/Output Leakage Current (SWITCH OFF)	6.0	GND	V_{OS}= V_{CC} or GND V_{IS} = V_{CC} or GND V_{IN} = V_{IHC} or V_{ILC}			±0.06		± 0.6		± 2	µA
		6.0	-6.0				± 0.1		± 1		± 2	
I_{IZ}	Switch Input Leakage Current (SWITCH ON, OUTPUT OPEN)	6.0	GND	V_{OS}= V_{CC} or GND V_{IN} = V_{IHC} or V_{ILC}			±0.06		± 0.6		± 2	µA
		6.0	-6.0				± 0.1		± 1		± 2	
I_{IN}	Control Input Current	6.0	V_I = V_{CC} or GND			10^{-5}	± 0.1		± 1		± 1	µA

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input $t_r = t_f$ = 6ns)

Symbol	Parameter	Test Condition			Value							Unit
		V_{CC} (V)	V_{EE} (V)		T_A = 25°C			-40 to 85°C		-55 to 125°C		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
$\Phi_{I/O}$	Phase Difference Between Input and Output	2.0	GND			12	30		40			ns
		4.5	GND			3	6		8			
		6.0	GND			3	5		7			
		4.5	-4.5			2	4		5			
		6.0	-6.0			2	4		5			
t_{PZL} t_{PZH}	Output Enable Time ($\overline{E}$, C - OUT)	2.0	GND	R_L = 1KΩ		56	115		145			ns
		4.5	GND			14	23		29			
		6.0	GND			12	20		25			
		4.5	-4.5			13	21		26			
		6.0	-6.0			11	18		23			
t_{PLZ} t_{PHZ}	Output Disable Time ($\overline{E}$, C - OUT)	2.0	GND	R_L = 1KΩ		112	205		255			ns
		4.5	GND			28	41		51			
		6.0	GND			24	35		43			
		4.5	-4.5			24	34		43			
		6.0	-6.0			21	29		36			
f_{MAX}	Maximum Control Input Frequency	2.0	GND	R_L = 1KΩ		2						MHz
		4.5	GND	C_L = 15 pF		9						
		6.0	GND	V_{OUT} = 1/2 V_{CC}		11						

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition		Value							Unit
		V_{CC} (V)		T_A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
C_{IN}	Input Capacitance				5	10		10		10	pF
$C_{I/O}$	Switch Terminal Capacitance	4.5	-4.5		5						pF
C_{IOS}	Feed Through Capacitance	4.5	-4.5		1						pF
C_{PD}	Power Dissipation Capacitance (note 1)	5.0	GND		16						pF

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$

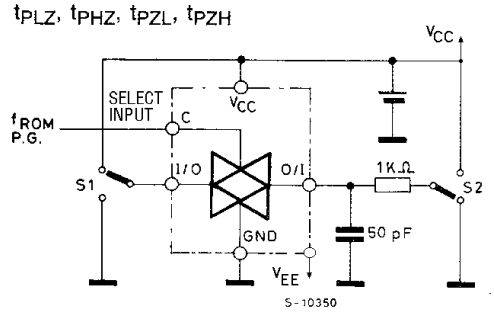
ANALOG SWITCH CHARACTERISTICS (GND = 0V;T_A = 25°C)

Symbol	Parameter	Test Condition				Value	Unit
		V_{CC} (V)	V_{EE} (V)	V_{IN} (V_{p-p})		Typ.	
	Sine Wave Distortion (THD)	2.25	2.25	4	f_{IN} = 1 KHz R_L = 10 KΩ, C_L = 50 pF	0.025	%
		4.5	4.5	8		0.020	
		6.0	6.0	11		0.018	
f_{MAX}	Frequency Response (Switch ON)	2.25	2.25	Adjust f_{IN} voltage to obtain 0 dBm at V_{OS}. Increase f_{IN} Frequency until dB meter reads -3dB R_L = 50Ω, C_L = 10 pF, f_{IN} = 1MHz sine wave		28	MHz
		4.5	4.5			42	
		6.0	6.0			43	
	Feed through Attenuation (Switch OFF)	2.25	2.25	V_{IN} is centered at V_{CC}/2. Adjust input for 0 dBm R_L = 600Ω, C_L = 50 pF, f_{IN} = 1MHz sine wave		-50	dB
		4.5	4.5			-50	
		6.0	6.0			-50	
	Crosstalk (Control Input to Signal Output)	2.25	2.25	R_L = 600Ω, C_L = 50 pF, f_{IN} = 1MHz square wave (t_r = t_f =6ns)			mV
		4.5	4.5			5	
		6.0	6.0				
	Crosstalk (Between Any Switches)	2.25	2.25	Adjust V_{IN} to Obtain 0 dBm at input R_L = 600Ω, C_L = 50 pF, f_{IN} = 1MHz sine wave		-50	dB
		4.5	4.5			-50	
		6.0	6.0			-50	

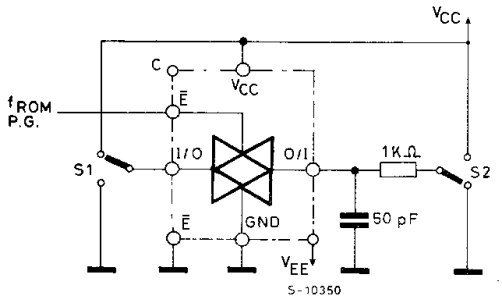
SWITCHING CARACTERISTICS TEST CIRCUIT

CONTROL

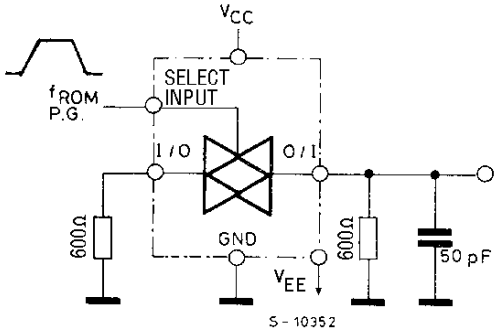
t_{PLZ}, t_{PHZ}, t_{PZL}, t_{PZH}



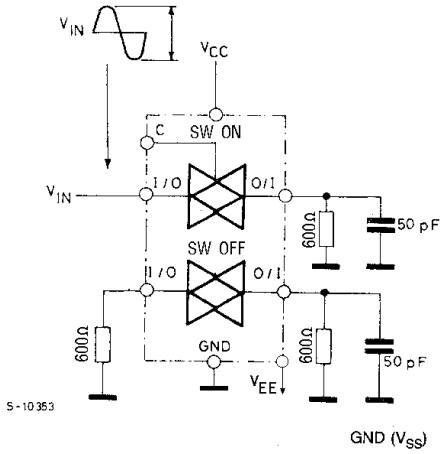
ENABLE



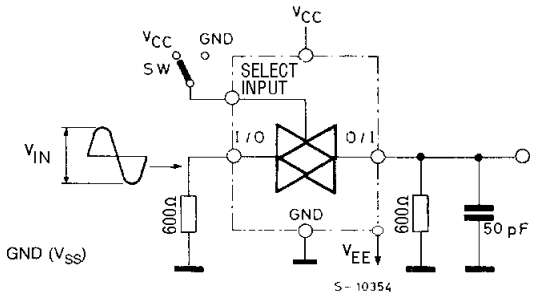
CROSSTALK (control to output)



CROSSTALK BETWEEN ANY TWO SWITCHES

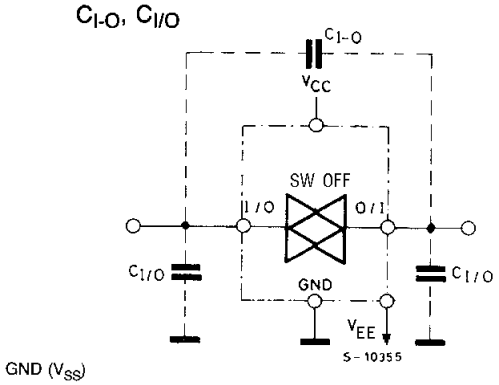


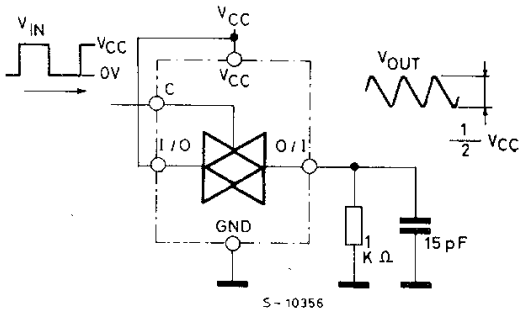
BANDWIDTH AND FEEDTHROUGH ATTENUATION



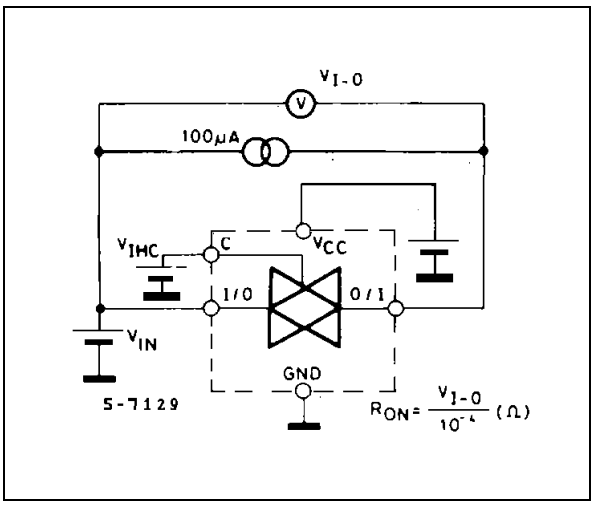
MAXIMUM CONTROL FREQUENCY

C_{I-O}, $C_{I/O}$

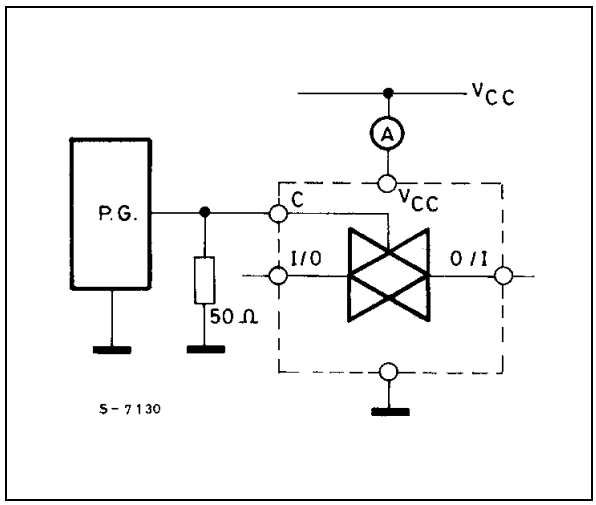




CHANNEL RESISTANCE (R_{ON})

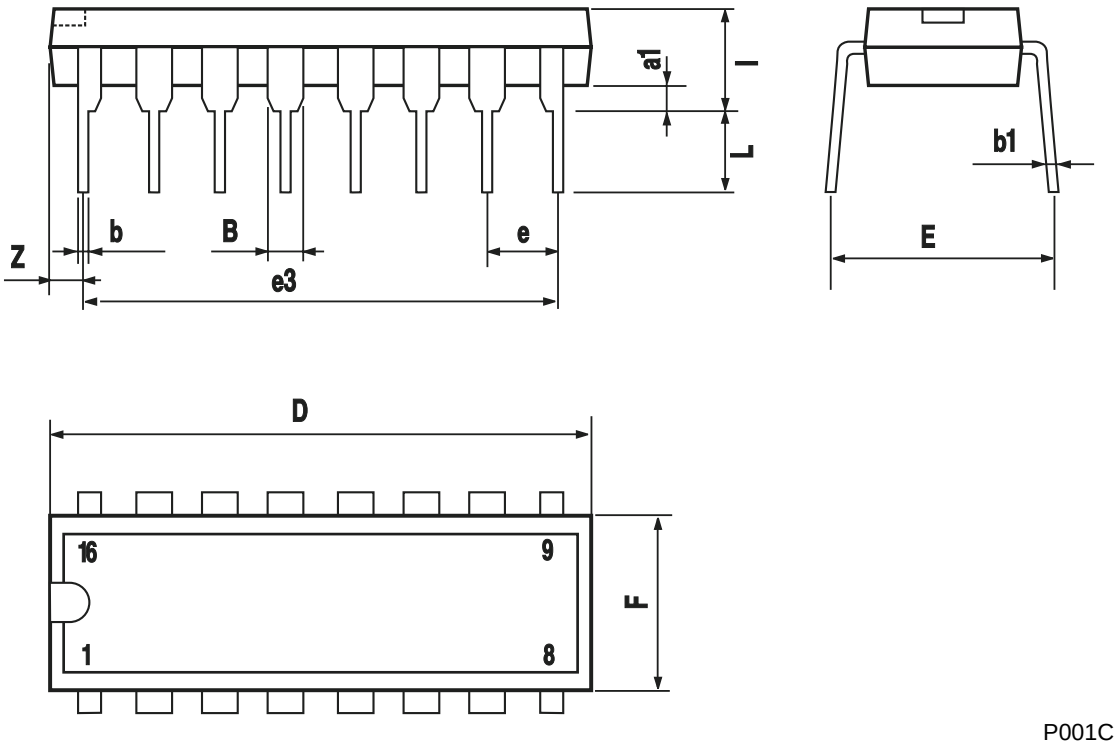


I_{CC} (Opr.)



Plastic DIP-16 (0.25) MECHANICAL DATA

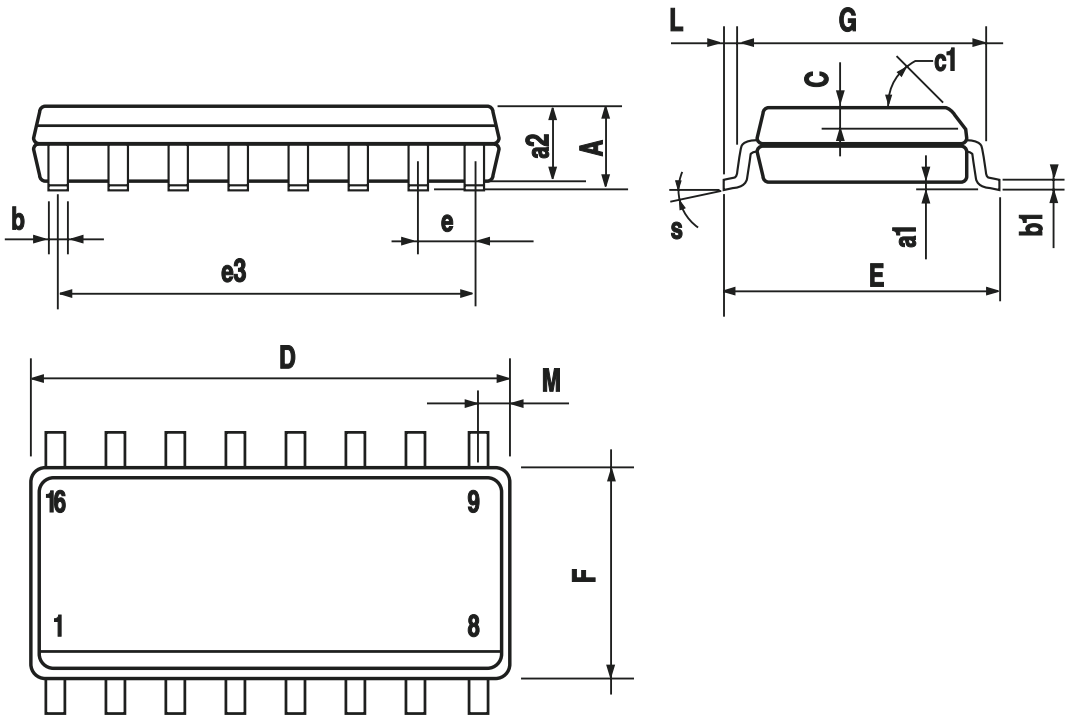
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



P001C

SO-16 MECHANICAL DATA

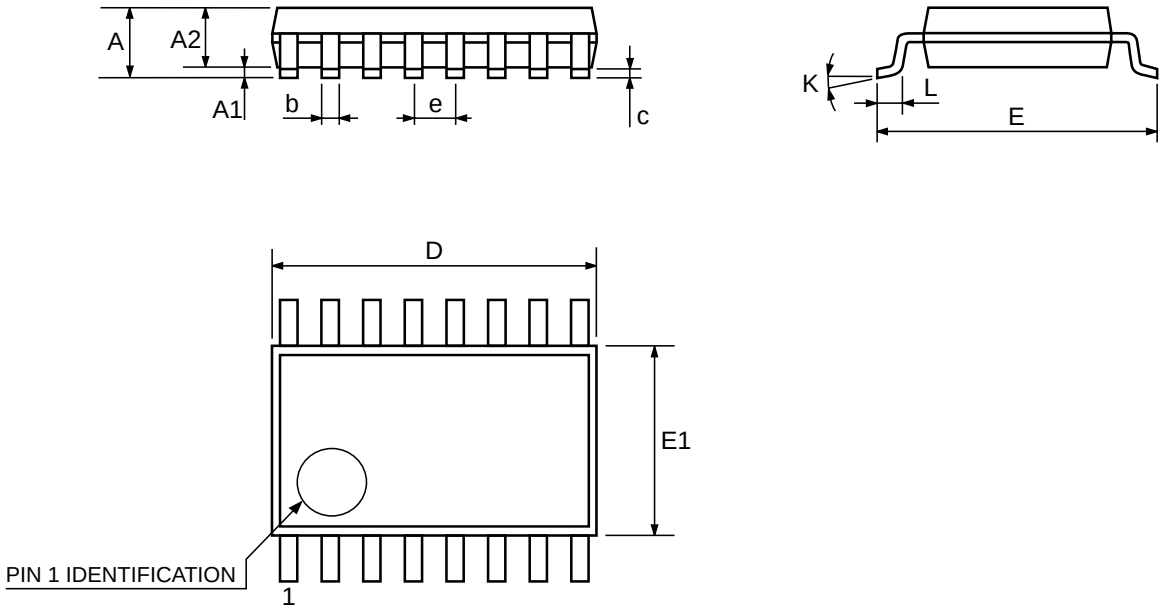
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					



PO13H

TSSOP16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



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